



## SOD-323 Plastic-Encapsulate Diodes

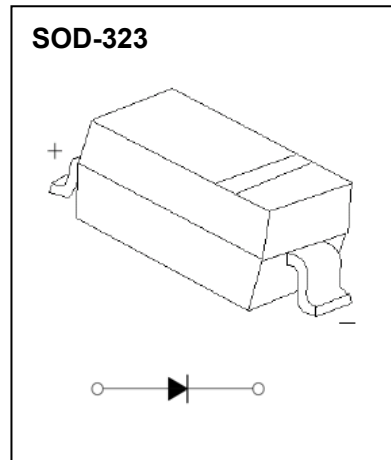
**RB550V-30** Schottky Barrier Diode

### FEATURES

- Small Surface Mounting Type
- Low  $V_F$  and  $I_R$
- High Reliability

### APPLICATIONS

- General Rectification



**MARKING: SS**

### MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ unless otherwise noted )

Symbol	Parameter	Value	Unit
$V_{RM}$	Non-Repetitive Peak Reverse Voltage	30	V
$I_O$	Continuous Forward Current	1	A
$I_{FSM}$	Forward Peak Surge Current@=8.3ms	3	A
$P_D$	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	500	$^\circ\text{C}/\text{W}$
$T_j$	Junction Temperature	125	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^\circ\text{C}$

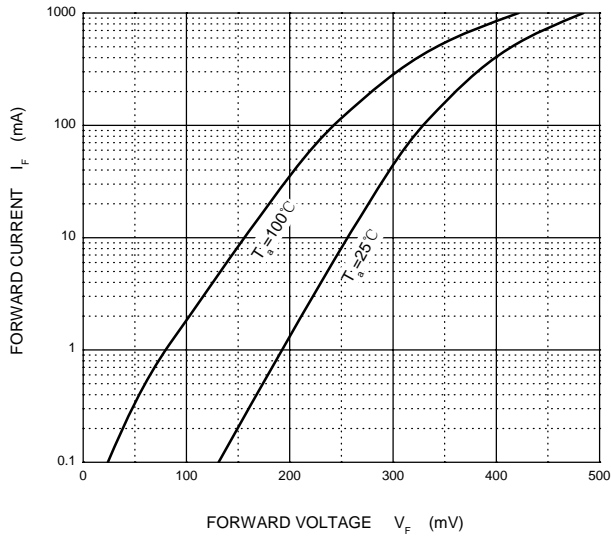
### ELECTRICAL CHARACTERISTICS( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R = 1\text{mA}$	30			V
Reverse current	$I_R$	$V_R = 10\text{V}$			0.03	mA
Forward voltage	$V_F$	$I_F = 700\text{mA}$			0.49	V
		$I_F = 1\text{A}$			0.52	

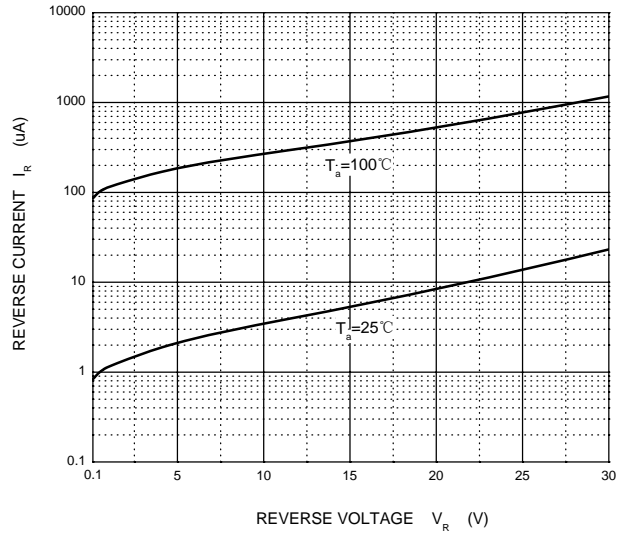
# Typical Characteristics

# RB550V-30

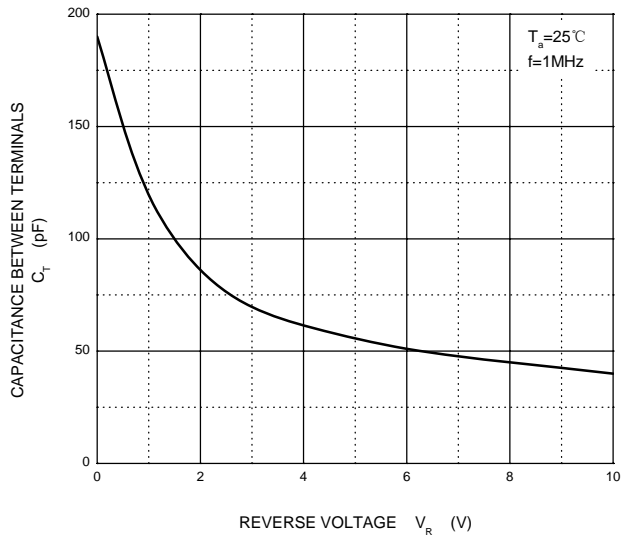
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

